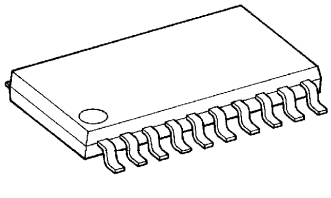
TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA4301F

DOWN CONVERTER FOR BS TUNER IC

FEATURES

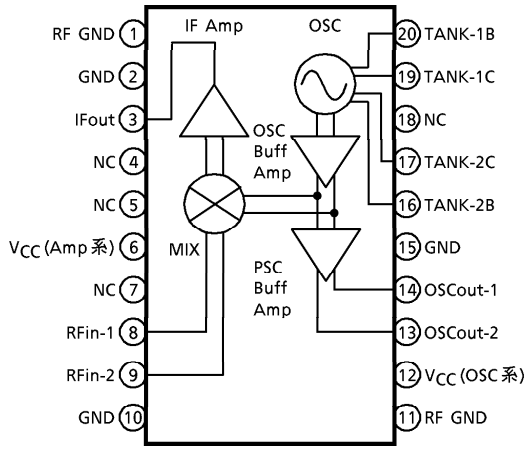
- Wide band operation (~1.6GHz)
- Operating supply voltage V_{CC} = 5V
- OSC output pin and connect with PLL IC
- SSOP 20 pin small package



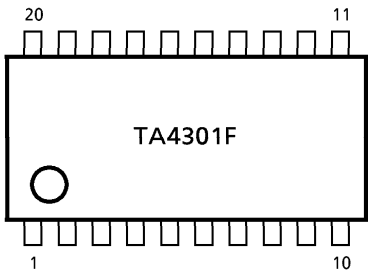
SSOP20-P-225-1.00

Weight : 0.17g (Typ.)

PIN CONNECTION FUNCTION BLOCK DIAGRAM

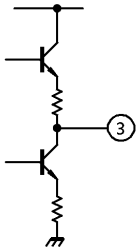
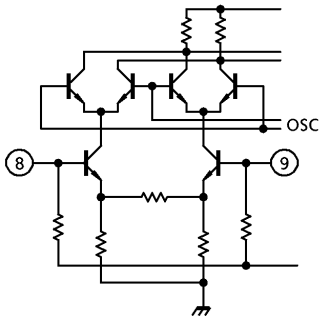
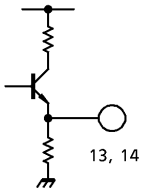


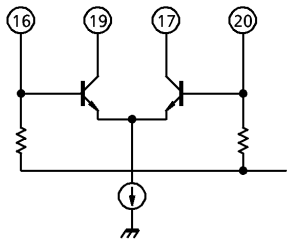
MARKING



980508EBA1

EXPLANATION

PIN No.	PIN NAME	PIN VOLTAGE	EXPLANATION	EQUIVALENT CIRCUIT
1	RF GND	0	GND Pin for OSC, OSC Buff Amp, PSC Buff Amp	—
2	GND	0	GND Pin for IF Amp, MIX	—
3	IFout	2.25	IF Output PIN	
4	NC	—	—	—
5	NC	—	—	—
6	V_{CC} (Amp)	5.0	Supply Voltage for MIX, IF Amp	—
7	NC	—	—	—
8	RFin-1	1.74	RF Input Pin	
9	RFin-2	1.74		
10	GND	0	GND Pin for IF Amp, MIX	—
11	RF GND	0	GND Pin for PSC Buff Amp	—
12	V_{CC} (OSC)	4.35	Supply Voltage Pin for OSC, OSC Buff Amp, PSC Buff Amp, Req.	—
13	OSCout-2	1.36	OSC Output Pin 2	
14	OSCout-1	1.36	OSC Output Pin 1	
15	GND	0	GND Pin for OSC, OSC Buff Amp, PSC Buff Amp, Req.	—

PIN No.	PIN NAME	PIN VOLTAGE	EXPLANATION	EQUIVALENT CIRCUIT
16	TANK-2B	1.4	Base Pin for OSC	
17	TANK-2C	3.28	Collector Pin for OSC	
18	NC	—	—	
19	TANK-1C	3.28	Collector Pin for OSC	
20	TANK-1B	1.4	Base Pin for OSC	

MAXIMAM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Supply Voltage	For Amp	V_{CC} (Amp)	6	V
	For OSC	V_{CC} (OSC)	5.5	
Total Power Dissipation		P_D (Note)	1100	mW
Operating Temperature		T_{opr}	−20~85	°C
Storage Temperature		T_{stg}	−45~150	°C

(Note) 100cm^2 × 1.6t (Cu layer area : 36%) on glass epoxy resins.

RECOMMENDED OPERATING RANGE

CHARACTERISTIC	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC} (Amp)	4.5~5.5	V
Supply Voltage	V_{CC} (OSC)	4.2~5.0	V
Input Frequency Range	fin	900~1600	MHz
IF Input Frequency Range	fIF	350~550	MHz

ELECTRIC CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CIR-CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Current	I_{CC} (Amp)	1	V_{CC} = 5V, No RF input	29	32	41	mA
Supply Current	I_{CC} (OSC)	1	V_{CC} = 4.35V, No RF input	29	36	45	mA
C. Gain	Gc	1	fin = 1.6GHz, fIF = 400MHz	14	21	25	dB
Noise Figure	NF	1	fin = 1.6GHz, fIF = 400MHz	—	18	22	dB
Po (sat)	Po (sat)	1	fin = 1.6GHz, fIF = 400MHz	5	10	—	dBmW
IP3	IP3	1	fin = 1.596GHz, 1.6GHz fIF = 400MHz, 404MHz	12	17	24	dBmW
Posc	Posc	1	fLO = 1.6GHz	—	−4	—	dBmW

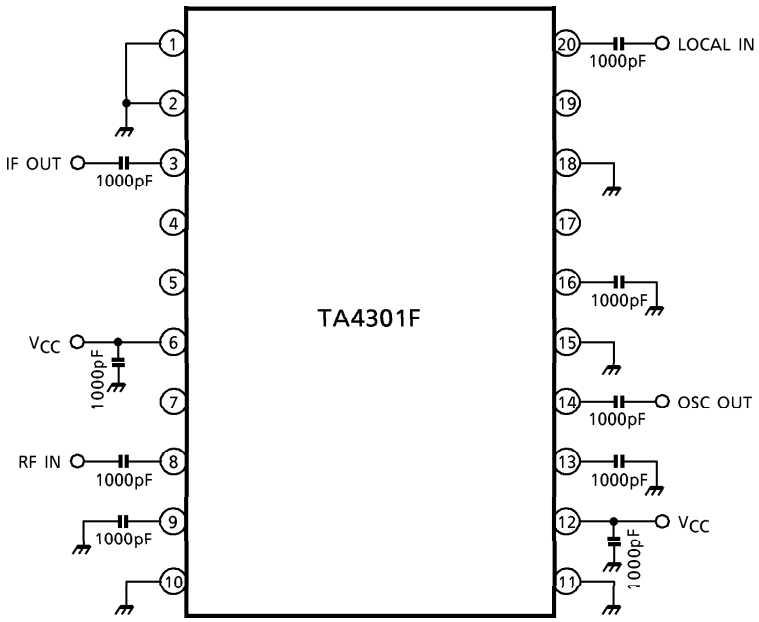
(Note) All electrical characteristics measured in Supply Voltage 5.0V / Amp, 4.35V / OSC.

(Reference characteristic)

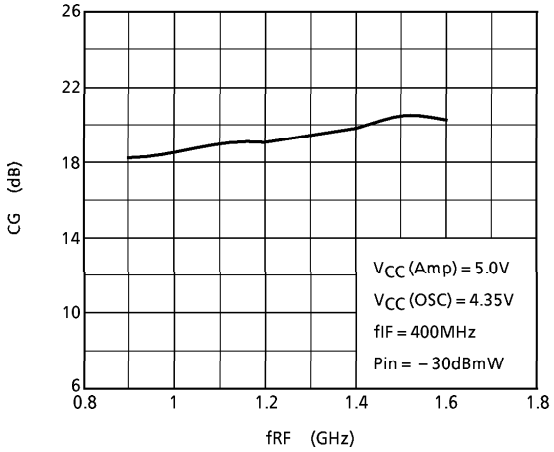
CHARACTERISTIC	TEST CONDITION	TYP.	UNIT
Rfin-LO Leak Level	fLO = 1.3GHz	−45	dBmW
Ifout-LO Leak Level	fLO = 1.3GHz	−20	dBmW
Input Returen Loss	fin = 1.6GHz	−4.5	dB
Output Return Loss	fLO = 1.3GHz	−5.0	dB

(Note) All electrical characteristics measured in Supply Voltage 5.0V / Amp, 4.35V / OSC.

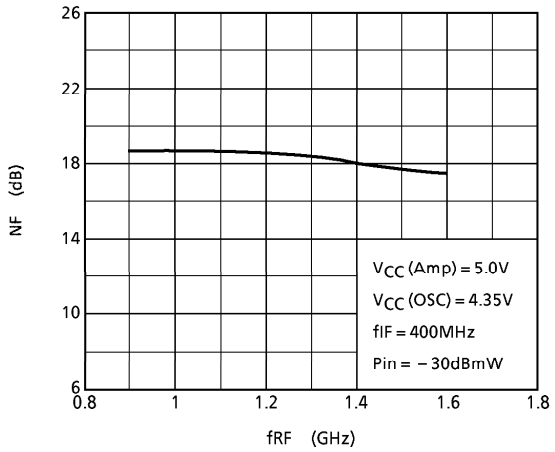
TEST CIRCUIT 1



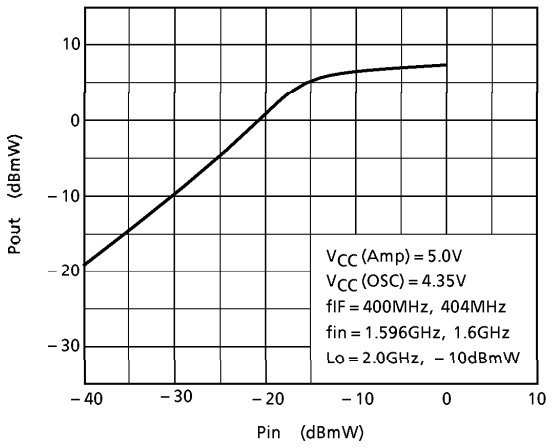
C. Gain – f



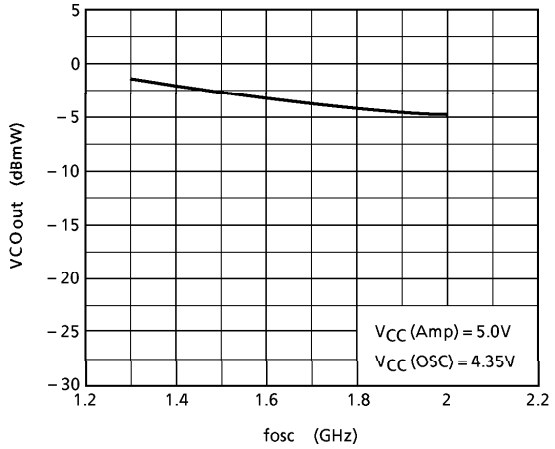
NF – f



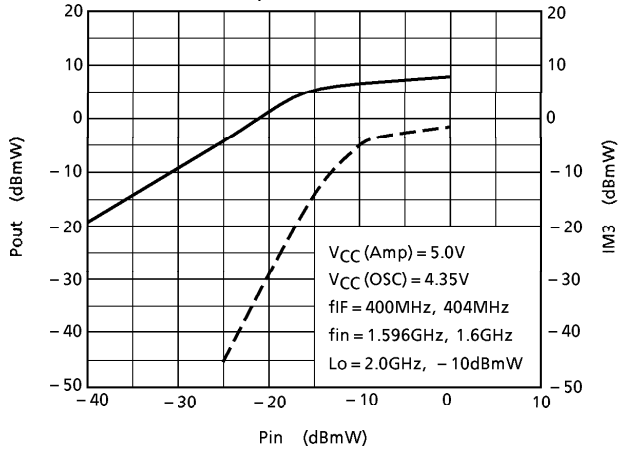
Pin – Pout



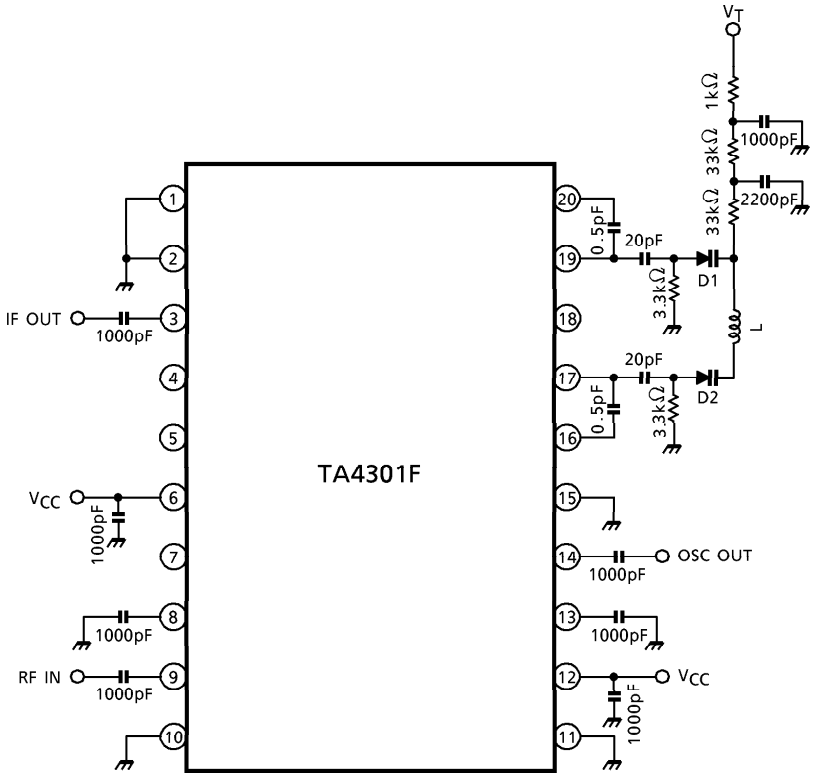
VCOout – f



Pin, IM3 – Pout



APPLICATION CIRCUIT

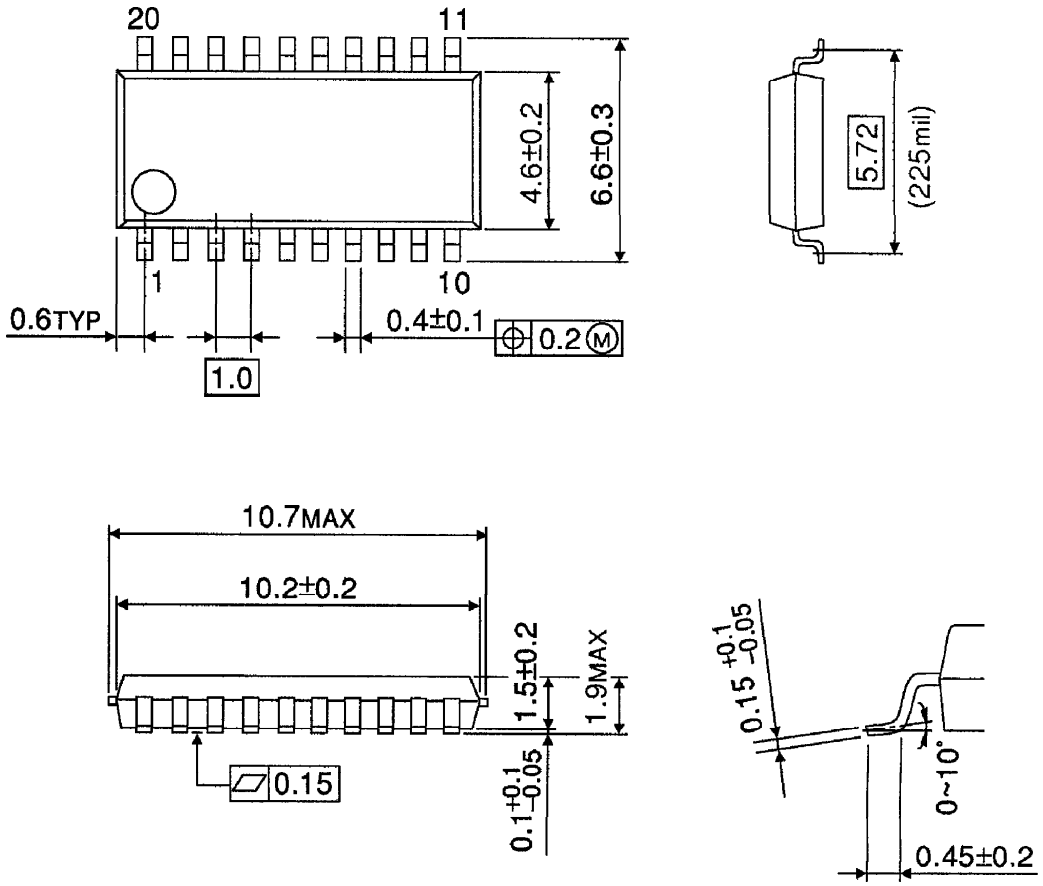


D1, D2 : 1SV245
L : COIL 0.3d, ϕ2.0, 1.5T (10nH)

OUTLINE DRAWING

SSOP20-P-225-1.00

Unit : mm



Weight : 0.17g (Typ.)